



## Rail-to-Rail Output, High Quality Audio, Dual Operational Amplifier

### ■ GENERAL DESCRIPTION

The MUSES8832 is a Rail-to-Rail output High quality audio operational amplifier, which is optimized for high-end audio and portable audio applications.

The MUSES8832 features 2.1nV/ $\sqrt{\text{Hz}}$  low noise, 10MHz wide gain bandwidth, 0.0009% low distortion, 600 $\Omega$  drive capability, -40°C to +125°C operating temperature range, and various reliabilities and conveniences are improved.

It is the best for audio preamplifiers, active filters, microphone amplifiers, and line amplifiers with excellent sound.

### ■ APPLICATIONS

- Home Audio
- PC Audio
- Portable Audio
- Car Audio

### ■ FEATURES

- Operating Voltage +2.7V to +14V  
 $\pm 1.35\text{V}$  to  $\pm 7.0\text{V}$
- Low Noise 2.1nV/ $\sqrt{\text{Hz}}$  typ. at f=1kHz  
0.3 $\mu\text{Vrms}$  typ. (20Hz to 20kHz)
- Output Current 32mA typ. (Capability of driving 600 $\Omega$  loads)
- GBW 10MHz typ.
- Low Distortion 0.0009% typ. at V+=+5V, Vo=1.3Vrms
- Slew Rate 1V/ $\mu\text{s}$  typ.
- Bipolar Technology
- Package Outline SOP8 JEDEC 150 mil, SSOP8-A3
- Operating Temperature Range -40 to +125°C

### ■ PACKAGE OUTLINE

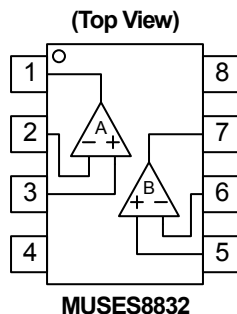


MUSES8832E  
(SOP8 JEDEC 150 mil)



MUSES8832VA3  
(SSOP8-A3)

### ■ PIN CONFIGURATION



#### PIN FUNCTION

1. A OUTPUT
2. A -INPUT
3. A +INPUT
4. V-
5. B +INPUT
6. B -INPUT
7. B OUTPUT
8. V+



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# MUSES8832

## ■ ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	$V^+$ ( $V^+V$ )	+15 ( $\pm 7.5$ )	V
Input Voltage	$V_{IN}$	+15 (Note1)	V
Differential Input Voltage	$V_{ID}$	$\pm 15$	V
Power Dissipation	$P_D$	SOP8 JEDEC 150 mil: 900 SSOP8-A3: 650(Note2)	mW
Operating Temperature Range	$T_{opr}$	-40 to +125	°C
Storage Temperature Range	$T_{stg}$	-65 to +150	°C

(Note1) For supply Voltages less than +15 V, the maximum input voltage is equal to the Supply Voltage.

(Note2) Mounted on the EIA/JEDEC standard board (114.3×76.2×1.6mm, two layer, FR-4).

## ■ RECOMMENDED OPERATING CONDITION (Ta=25°C)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Supply Voltage	$V^+$		+2.7	-	+14.0	V
	$V^+V$		$\pm 1.35$	-	$\pm 7.0$	V

## ■ ELECTRIC CHARACTERISTICS

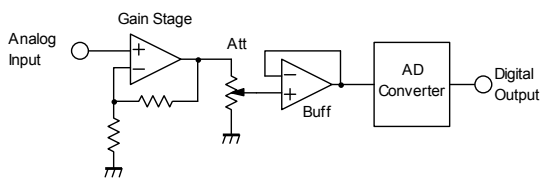
$V^+ = +5V$ ,  $V = 0V$ ,  $T_a = 25^\circ C$ ,  $R_L$  to  $V^+/2$ , unless otherwise specified

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Supply Current	$I_{CC}$	No Signal, $R_L = \infty$	-	7.5	10	mA
Power Dissipation	$P_D$	No Signal	-	42.5	60	mW
Input Offset Voltage	$V_{IO}$	$R_S = 50\Omega$	-	0.1	0.5	mV
Input Bias Current	$I_B$		-	4	6.5	$\mu A$
Input Offset Current	$I_{IO}$		-	100	500	nA
Open-Loop Voltage Gain	$A_V$	$R_L = 10k\Omega$ to $V^+/2$ , $V_O = 0.5$ to $4.5V$	90	115	-	dB
Common Mode Input Voltage Range	$V_{ICM}$	CMR $\geq 90$ dB	0.5	-	3.7	V
Common Mode Rejection Ratio	CMR	$R_S = 50\Omega$	90	110	-	dB
Supply Voltage Rejection Ratio	SVR	$R_S = 50\Omega$	90	105	-	dB
Maximum Output Voltage 1	$V_{OH1}$	$R_L = 10k\Omega$ to $0V$	4.9	4.95	-	V
	$V_{OL1}$	$R_L = 10k\Omega$ to $0V$	-	0.05	0.1	V
Maximum Output Voltage 2	$V_{OH2}$	$R_L = 600\Omega$ to $V^+/2$	4.8	4.9	-	V
	$V_{OL2}$	$R_L = 600\Omega$ to $V^+/2$	-	0.1	0.2	V
Output Source Current	$I_{SOURCE}$	$V_O = V^+ - 0.5V$	10	32	-	mA
Output Sink Current	$I_{SINK}$	$V_O = 0.5V$	10	20	-	mA
Gain Bandwidth Product	GBW	$f = 10kHz$	-	10	-	MHz
Slew Rate	SR	$R_L = 2k\Omega$	-	1	-	V/ $\mu s$
Total Harmonic Distortion + Noise	THD+N	Gain=10, $V_O = 1.3V_{rms}$ , $R_L = 2k\Omega$ , $f = 1kHz$	-	0.0009	-	%
Channel Separation	CS	Gain=100, $R_S = 1k\Omega$ , $R_L = 10k\Omega$ , $f = 1kHz$	-	140	-	dB
Input Noise Voltage1	$e_n$	$f = 1kHz$	-	2.1	-	nV/ $\sqrt{Hz}$
Input Noise Voltage2	$V_n$	$f = 20Hz$ to $20kHz$	-	0.30	-	$\mu V_{rms}$

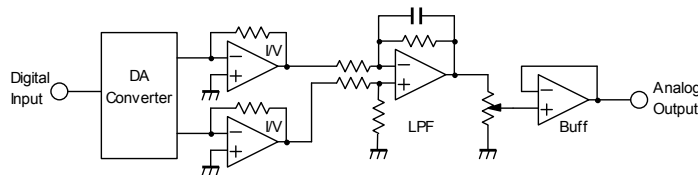
■ **NOTE**

1. The closed gain should be 6dB or higher to prevent the oscillation. Unity gain follower application may cause the oscillation.
2. Minimize the load capacitor for the better performance. A large load capacitor CL reduces the frequency response and causes oscillation or ringing.
3. Be careful to the circuit of high impedance. Input bias current influences an input noise and output offset voltage.

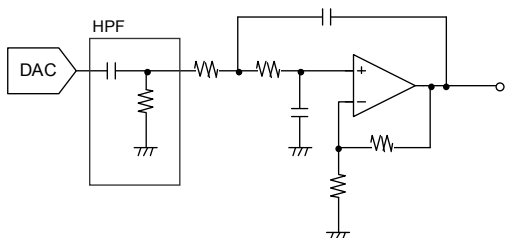
■ **APPLICATION CIRCUIT**



(Fig.1:ADC Input)



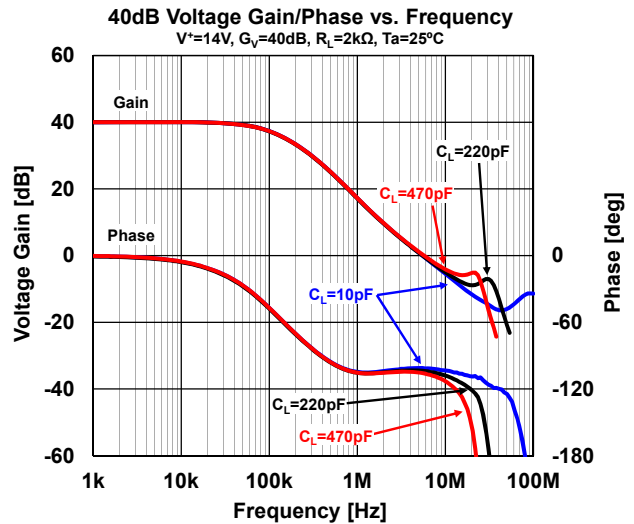
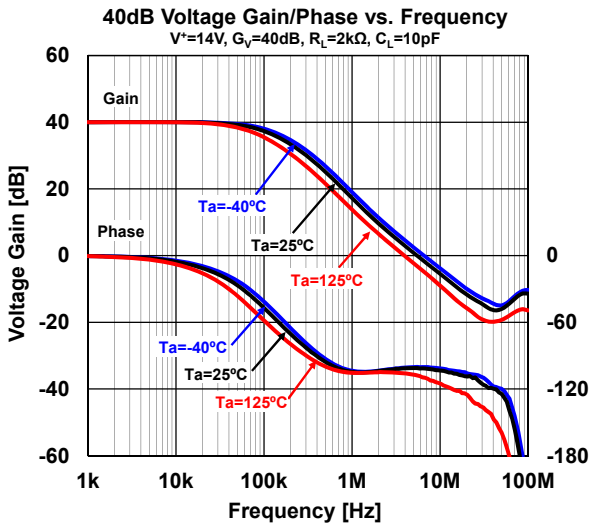
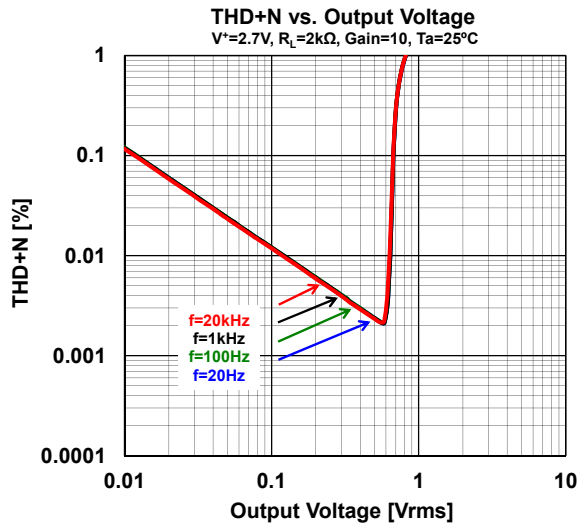
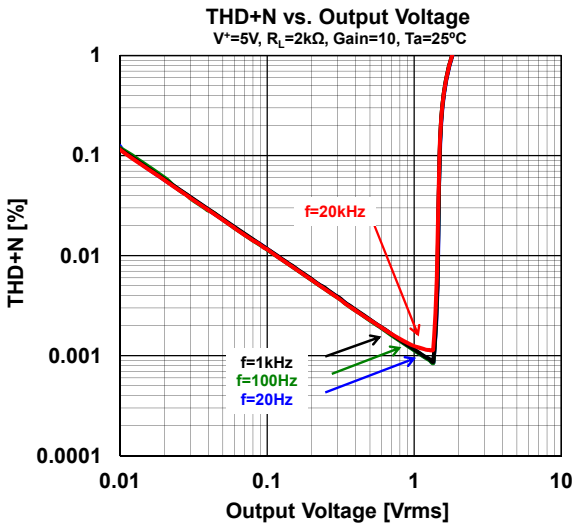
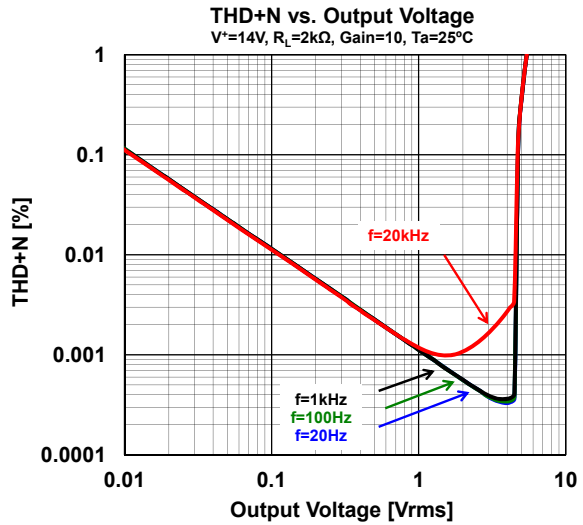
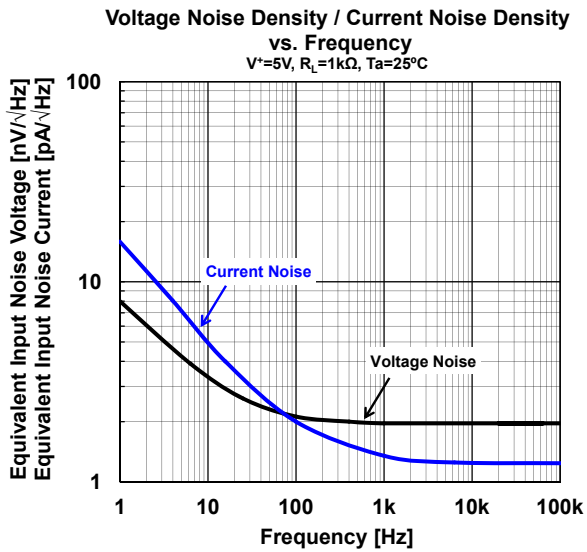
(Fig.2:DAC Output)



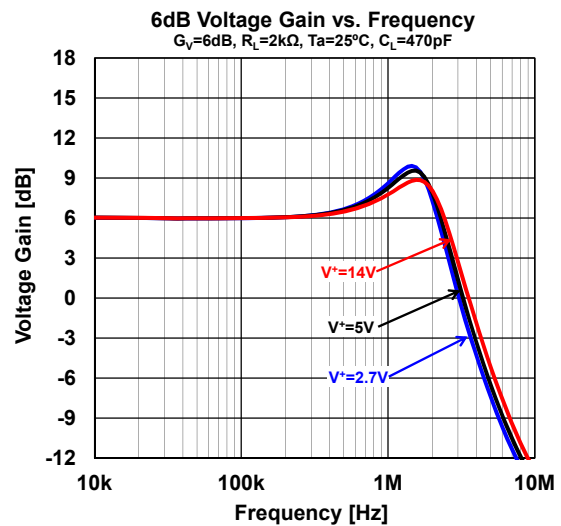
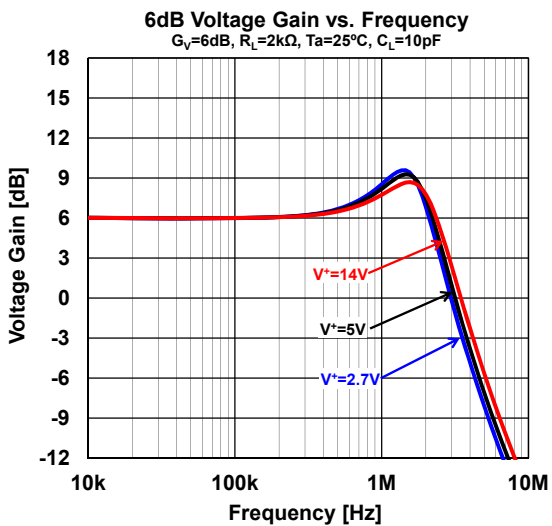
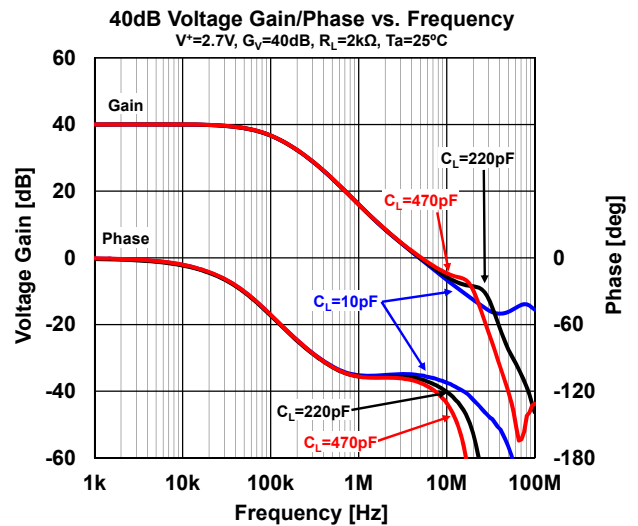
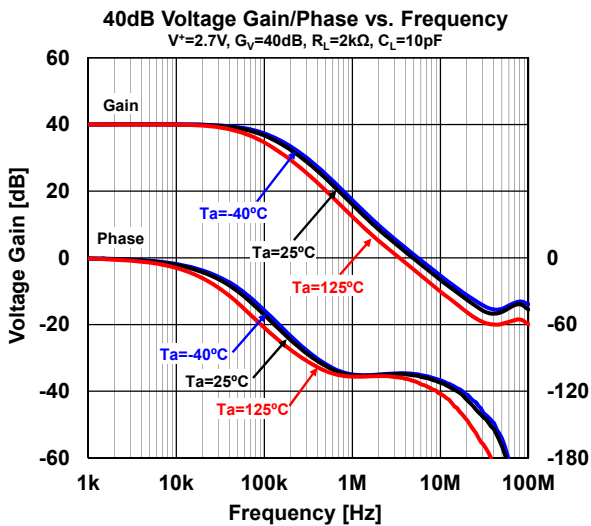
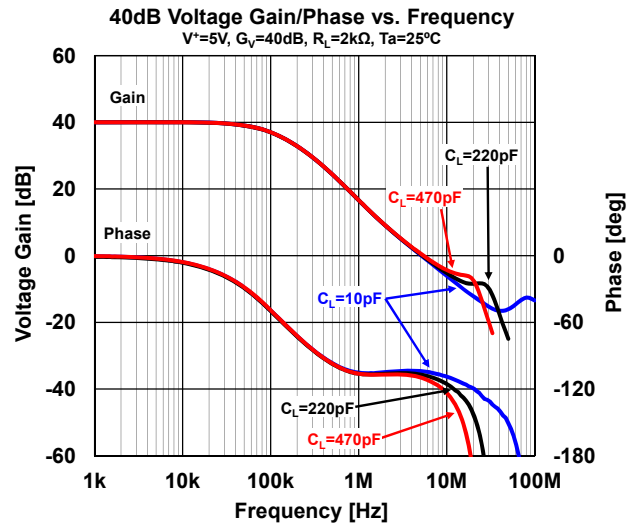
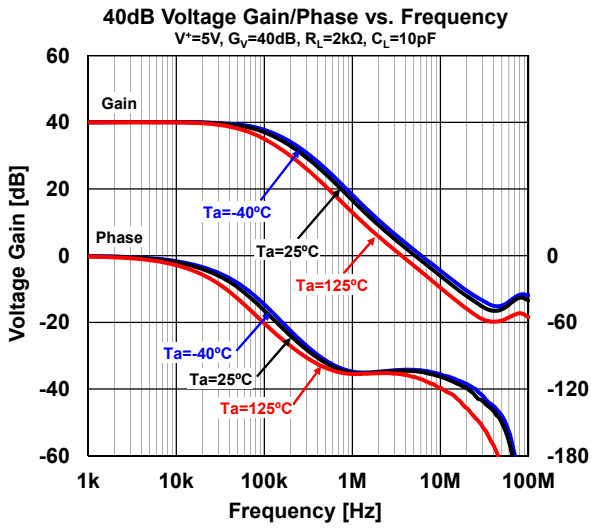
(Fig.3:DAC LPF Circuit )

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## ■ TYPICAL CHARACTERISTICS ( $V^- = 0V$ , $V_{CM} = V^+ / 2$ , unless otherwise specified)

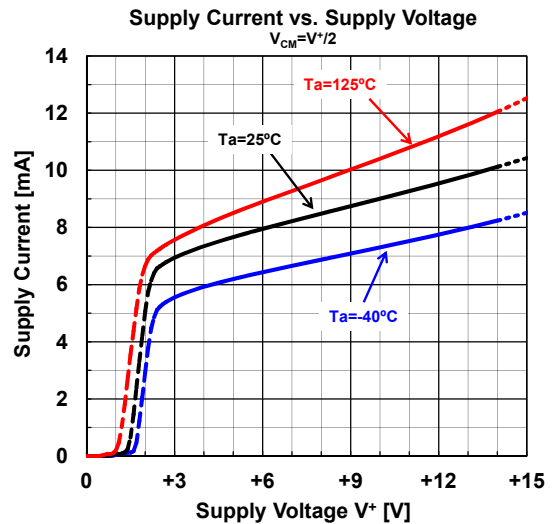
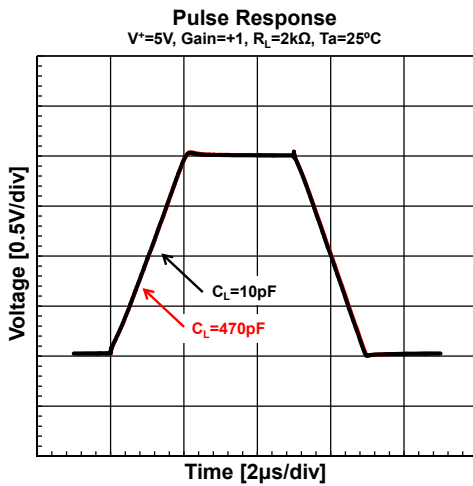
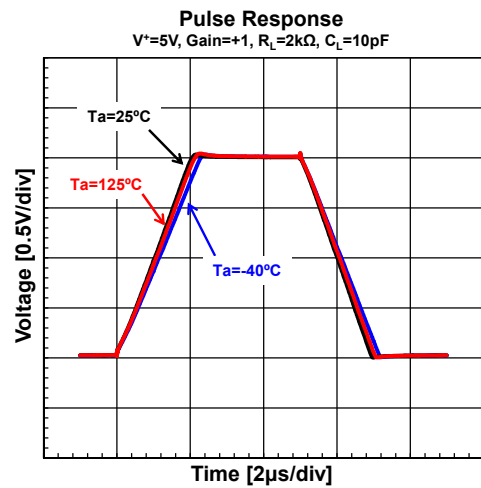
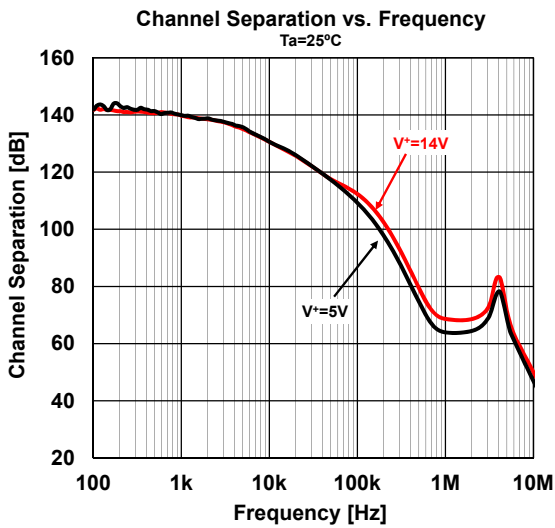
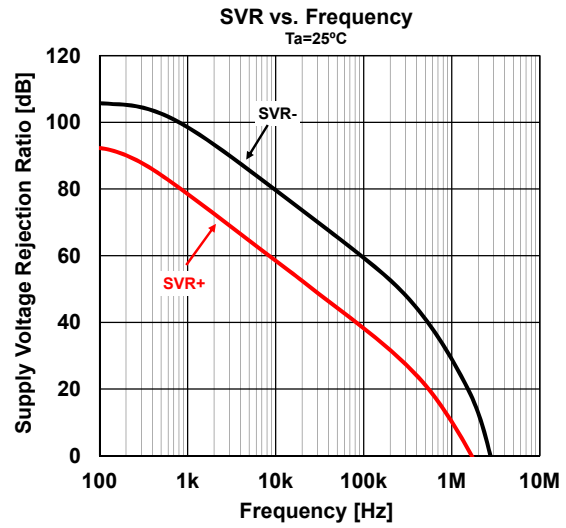
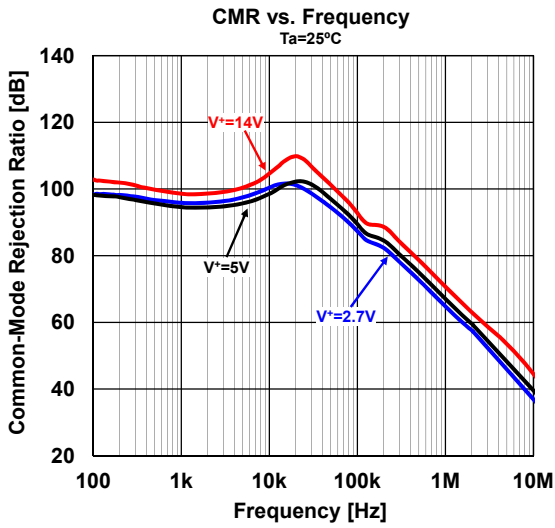


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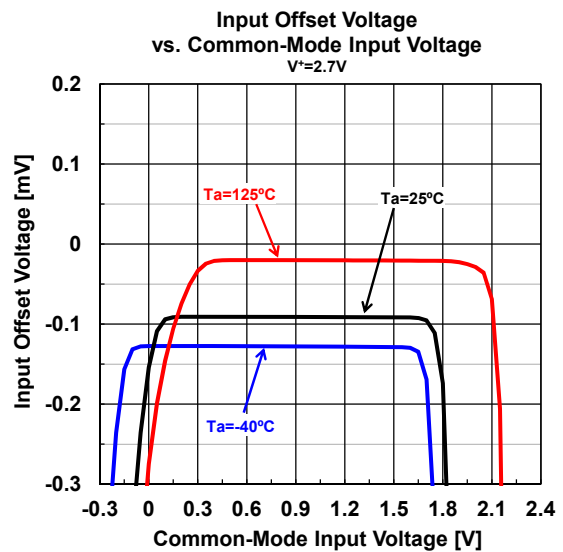
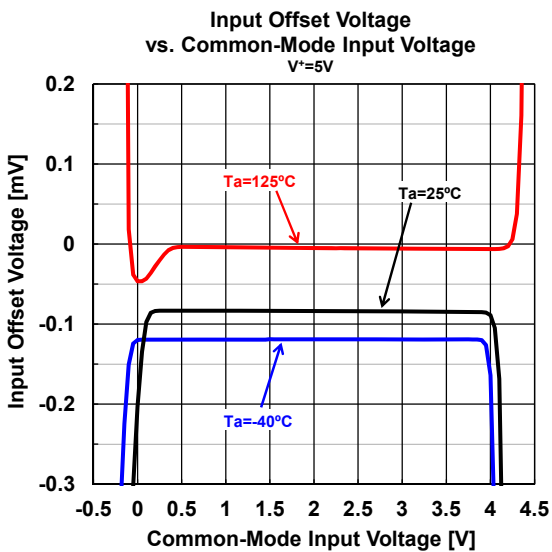
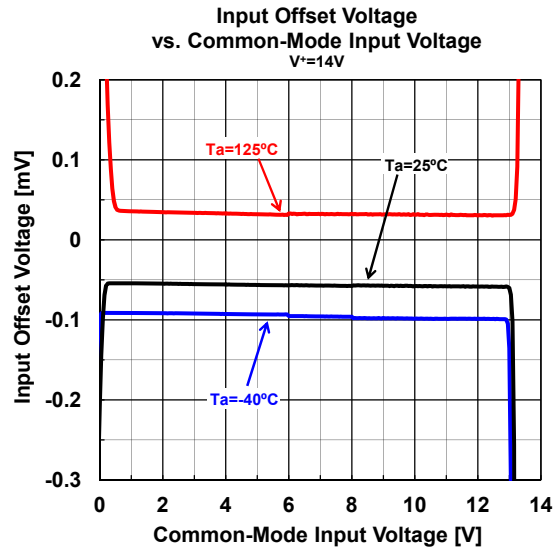
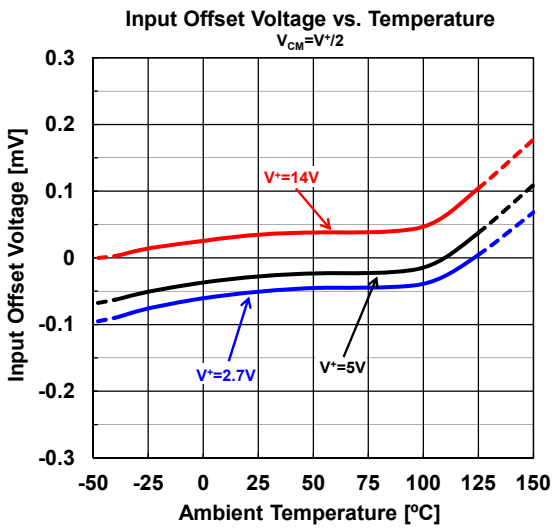
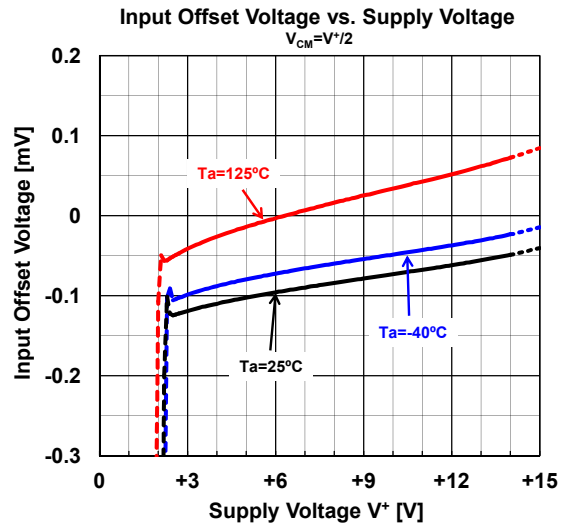
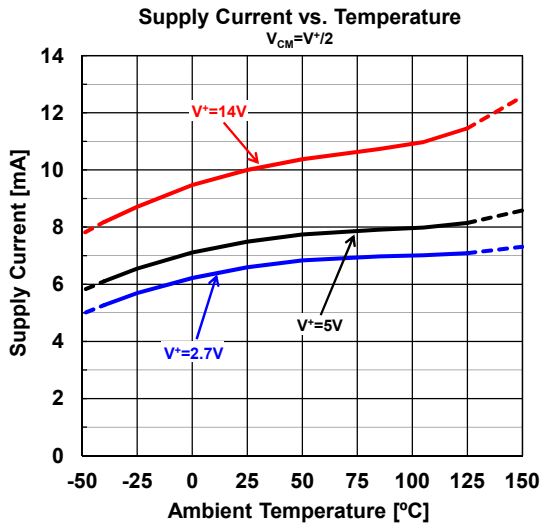


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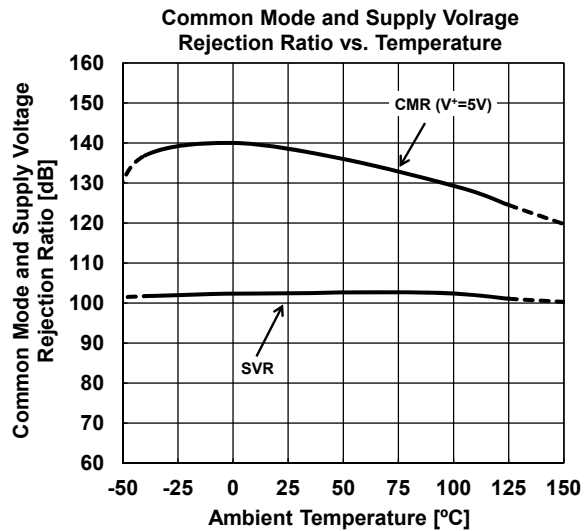
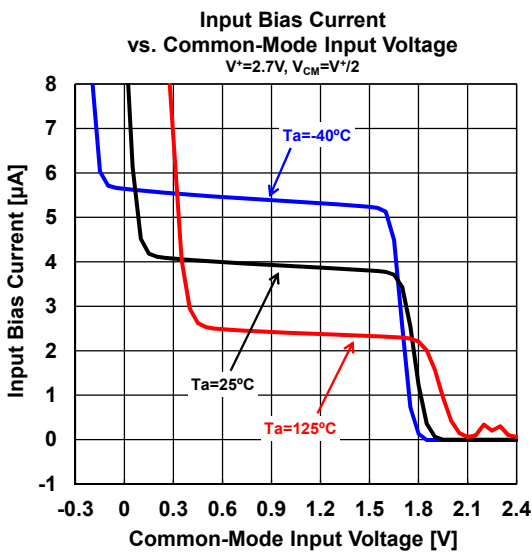
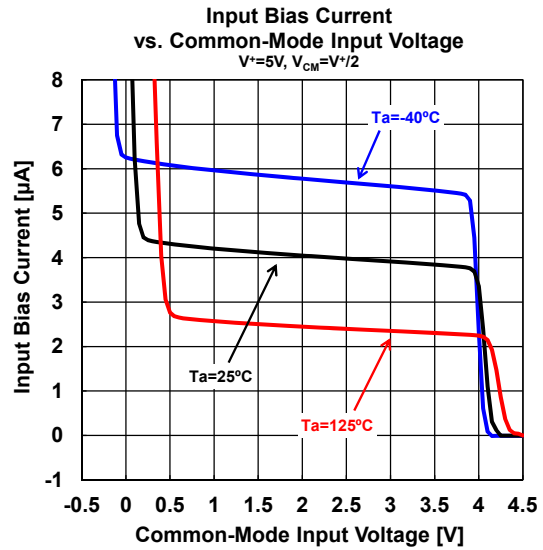
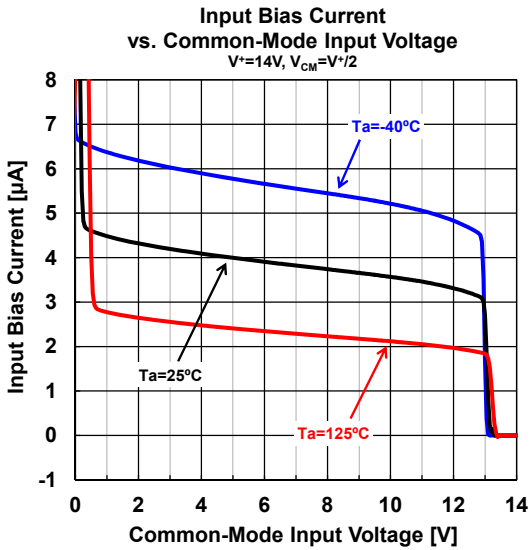
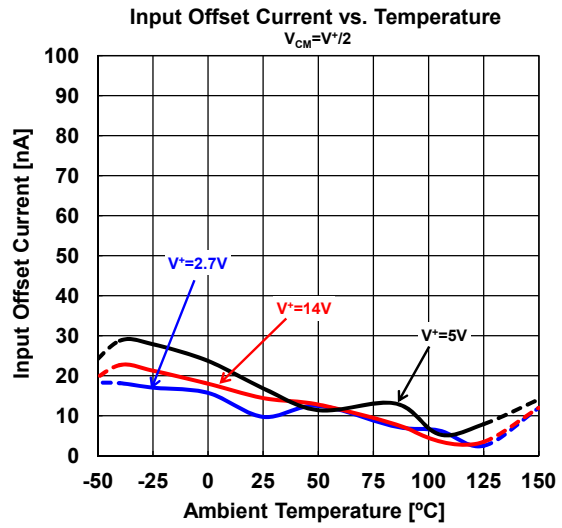
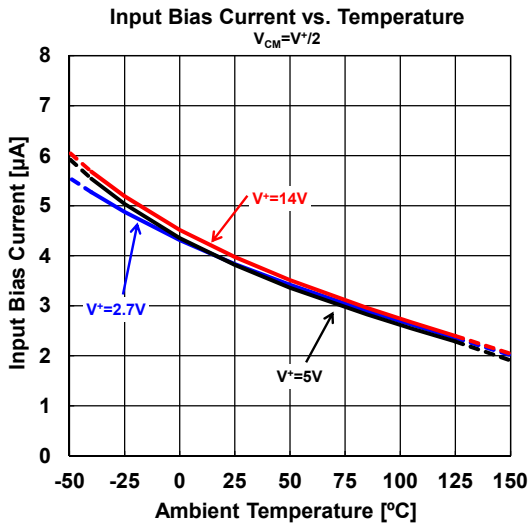


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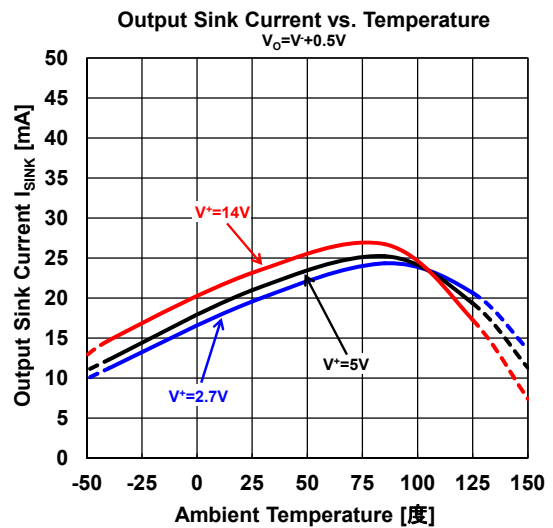
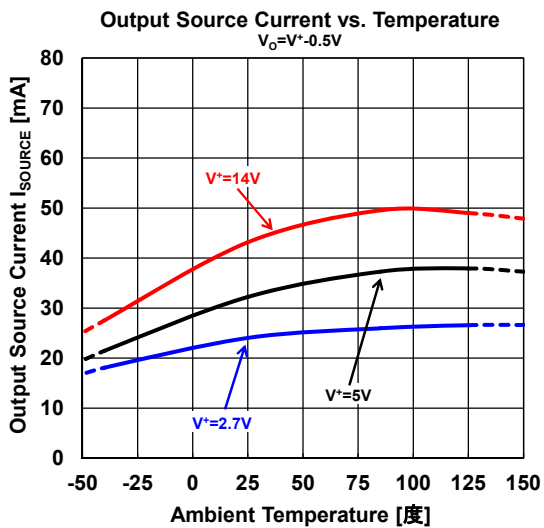
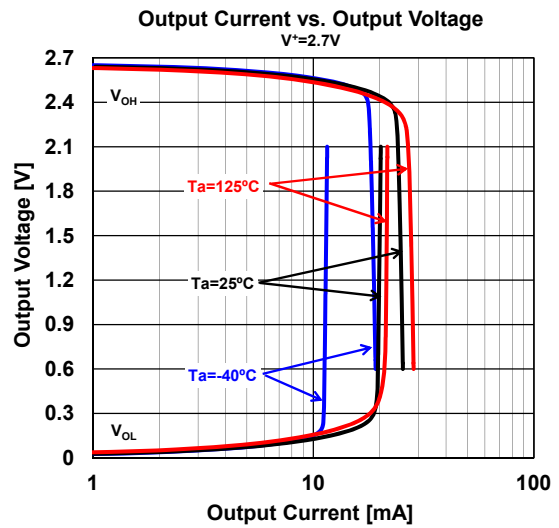
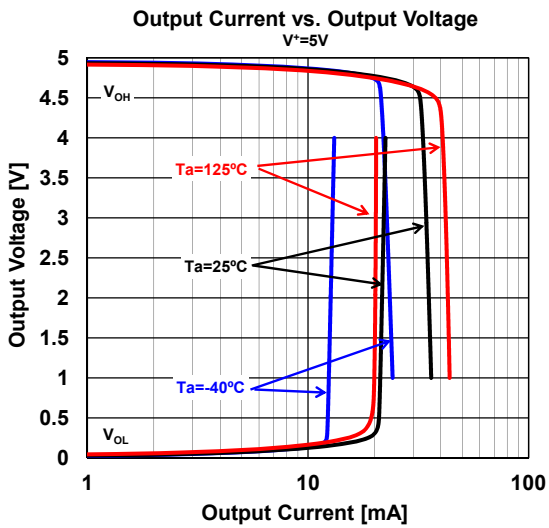
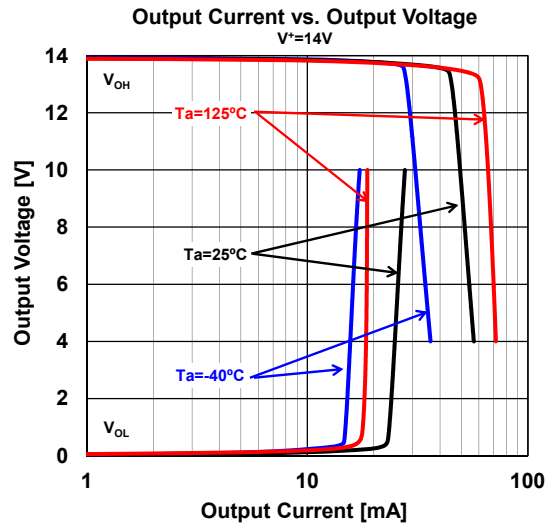
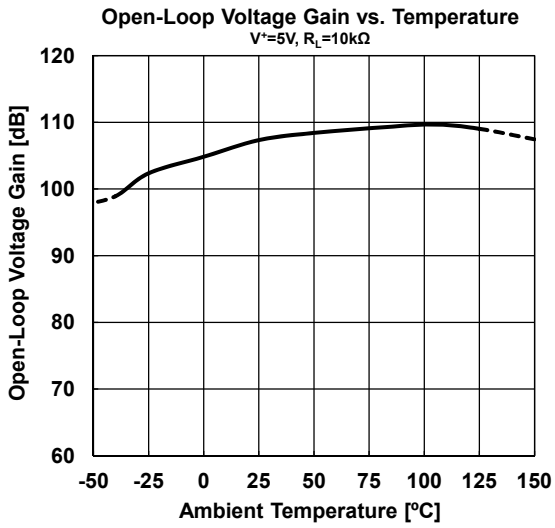
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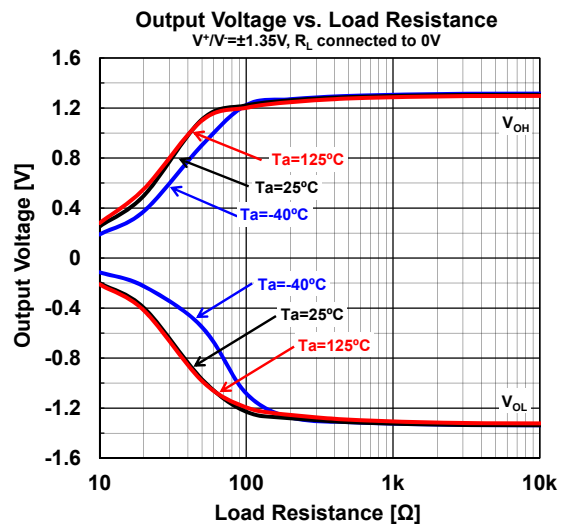
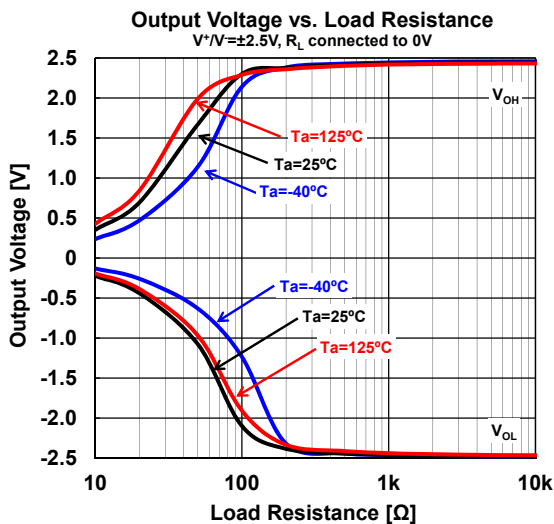
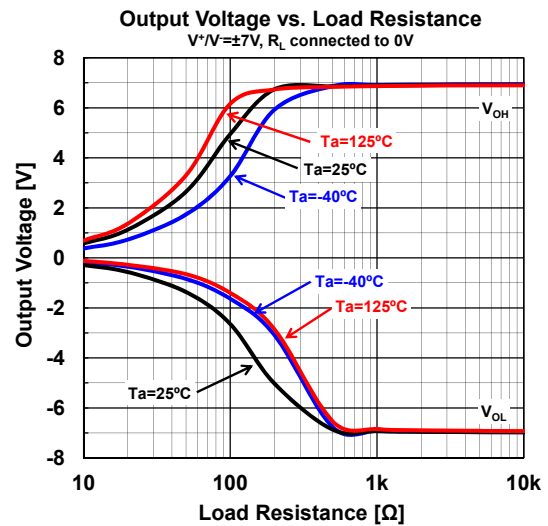
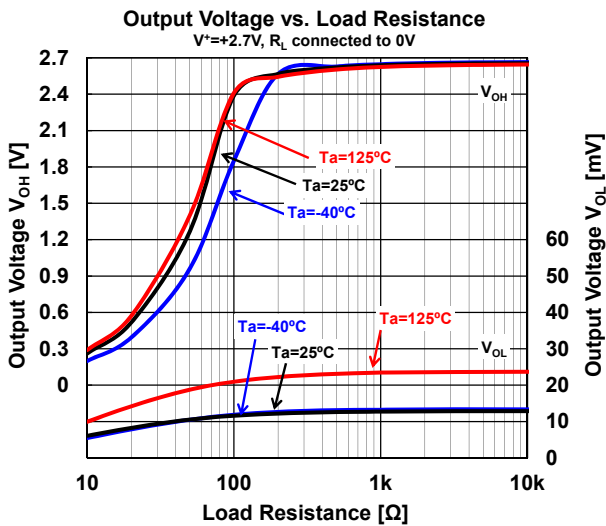
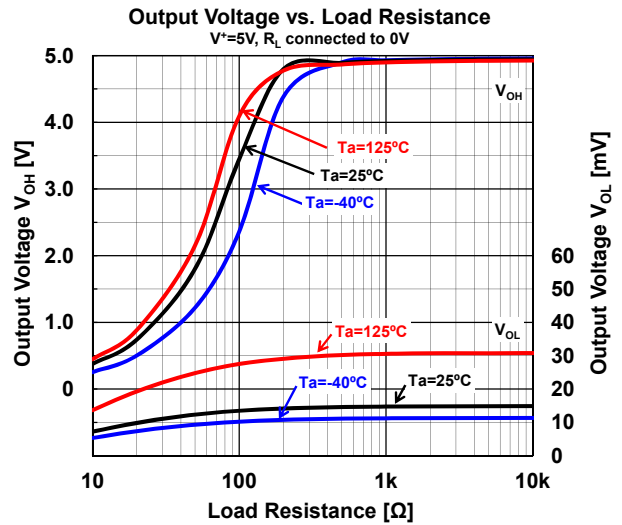
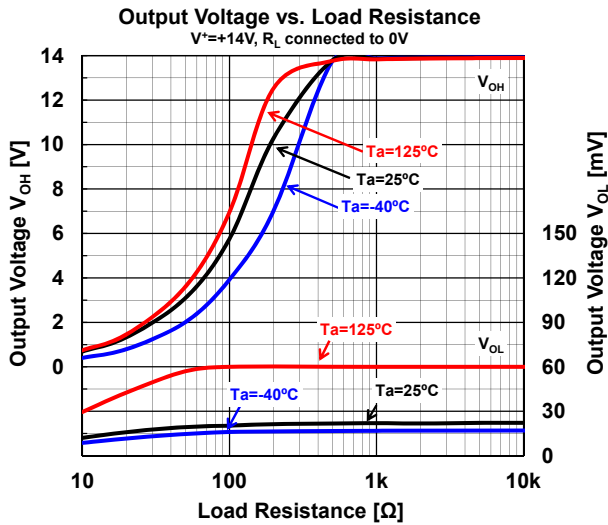


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# MUSES8832

## ■ TYPICAL CHARACTERISTICS ( $V^- = 0V$ , $V_{CM} = V^+ / 2$ , unless otherwise specified)



## ■ MEMO

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Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

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105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: [info@moschip.ru](mailto:info@moschip.ru)

Skype отдела продаж:

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